

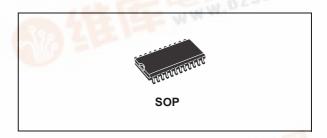
HCF4067B

ANALOG SINGLE 16 CHANNEL MULTIPLEXER

- LOW ON RESISTANCE : 125Ω (Typ.) OVER 15V p-p SIGNAL INPUT RANGE FOR VDD - VSS = 15V
- HIGH OFF RESISTANCE : CHANNEL LEAKAGE OF 10pA (Typ.) at V_{DD} V_{SS} = 10V
- MATCHED SWITCH CHARACTERISTICS : $\Delta R_{ON} = 5\Omega$ (Typ.) FOR $V_{DD} V_{SS} = 15V$
- VERY LOW QUIESCENT POWER
 DISSIPATION UNDER A DIGITAL CONTROL
 INPUT AND SUPPLY CONDITIONS: 0.2µW
 (Typ.) at V_{DD} V_{SS} = 10V
- BINARY ADDRESS DECODING ON CHIP
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT
 I_I = 100nA (MAX) AT V_{DD} = 18V T_A = 25°C
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B "STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"

DESCRIPTION

HCF4067B is monolithic integrated circuits fabricated in Metal Oxide Semiconductor technology available in SOP package.



ORDER CODES

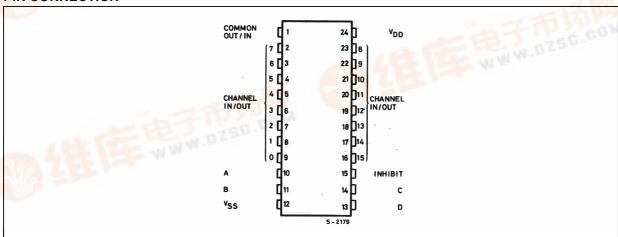
PACKAGE	TUBE	T & R
SOP	HCF4067BM1	HCF4067M013TR

HCF4067B, analog multiplexer/demultiplexer CMOS, is a digitally controlled analog switches device having low ON impedance, low OFF leakage current and internal address decoding. In addition, the ON resistance is relatively constant over the full input-signal range.

HCF4067B ia a 16-channel multiplexer with four binary control inputs A, B, C, D, and an inhibit input, arranged so that any combination of the inputs selects one switch.

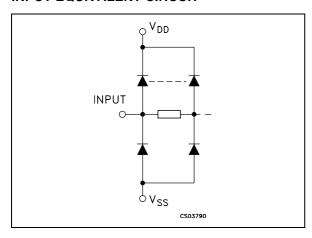
PIN CONNECTION

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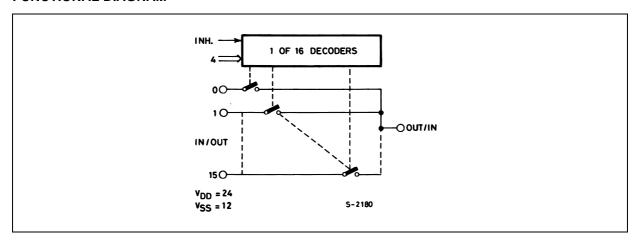
INPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
10, 11, 14, 13	A, B, C, D	Binary Control Inputs
1	COMMON OUT/IN	Common Out/In
15	INHIBIT	Inhibit Input
9, 8, 7, 6, 5, 4, 3, 2, 23, 22, 21, 20, 19, 18, 17, 16	0 to 15 CHANNEL IN/OUT	16 channel In/Out
12	V _{SS}	Negative Supply Voltage
24	V_{DD}	Positive Supply Voltage

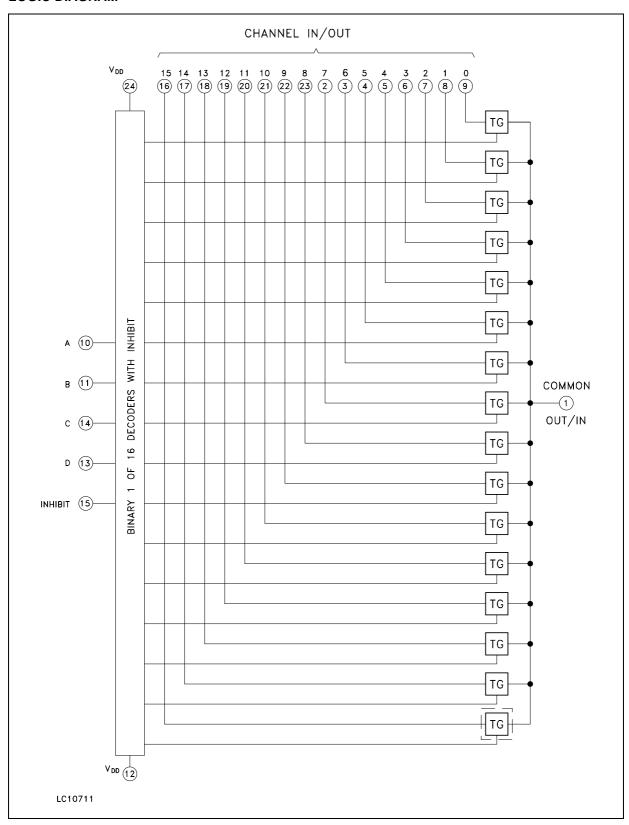
FUNCTIONAL DIAGRAM



TRUTH TABLE

Α	В	С	D	INH	SELECTED CHANNEL
Х	Х	Х	Х	Н	NONE
L	L	L	L	L	0
Н	L	L	L	L	1
L	Н	L	L	L	2
Н	Н	L	L	L	3
L	L	Н	L	L	4
Н	L	Н	L	L	5
L	Н	Н	L	L	6
Н	Н	Н	L	L	7
L	L	L	Н	L	8
Н	L	L	Н	L	9
L	Н	L	Н	L	10
Н	Н	L	Н	L	11
L	L	Н	Н	L	12
Н	L	Н	Н	L	13
L	Н	Н	Н	L	14
Н	Н	Н	Н	Ĺ	15

LOGIC DIAGRAM



HCF4067B

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{DD}	Supply Voltage	-0.5 to +22	V
V _I	DC Input Voltage	-0.5 to V _{DD} + 0.5	V
I _I	DC Input Current	± 10	mA
P _D	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T _{op}	Operating Temperature	-55 to +125	°C
T _{stg}	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V_{SS} pin voltage.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{DD}	Supply Voltage	3 to 20	V
VI	Input Voltage	0 to V _{DD}	V
T _{op}	Operating Temperature	-55 to 125	°C

STATIC ELECTRICAL CHARACTERISTICS

 $(T_{amb} = 25^{\circ}C, Typical temperature coefficient for all V_{DD} value is 0.3 \%/^{\circ}C)$

		Т	est Co	ndition					Value				
Symbol	Parameter	V _{IS}	V _{EE}	V _{SS}	V _{DD}	Т	T _A = 25°C		-40 to 85°C		-55 to	125°C	Unit
		(V)	(V)	(V)	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
ΙL	Quiescent Supply				5		0.04	5		150		150	
	Current				10		0.04	10		300		300	^
					15		0.04	20		600		600	μΑ
					20		0.08	100		3000		3000	
SWITCH													
R _{ON}	On Resistance	0 <u><</u> V _I			5		470	1050		1200		1200	
		∪ ≤ V _I ≤ V _{DD}	0	0	10		180	400		500		520	Ω
		_ > vDD			15		125	240		300		300	
Δ_{ON}	Resistance Δ_{RON}				5		10						
	(between any 2 of		0	0	10		10						Ω
	4 switches)				15		5						
OFF (•)	Channel Leakage Current Any Channel Off		0	0	18		±0.1	100		1000		1000	
	Channel Leakage Current All Channel Off (Common Out/In)		0	0	18		±0.1	100		1000		1000	μΑ
С	Capacitance Input						5						
	Output capacitance			-5	5		55						pF
	Feedthrough						0.2						
CONTRO	ÖL	•	•		•			•	•	•			
V_{IL}	Input Low Voltage		V _{EE} =	= V _{SS}	5			1.5		1.5		1.5	
			$R_1 = 1$		10			3		3		3	V
		= VDD thru	_ V	SS	15			4		4		4	
V_{IH}	Input High Voltage	1ΚΩ		μA (on	5	3.5			3.5		3.5		
				OFF	10	7			7		7		V
			chan	inels)	15	11			11		11		
П	Input Leakage Current	VI	= 0/18\	/	18		±10 ⁻³	±0.1		±1		±1	μΑ
C _I	Input Capacitance	Any Add	lress or Input	Inhibit			5	7.5					pF

The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD} =5V, 2V min. with V_{DD} =10V, 2.5V min. with V_{DD} =15V

[•] Determined by minimum feasible leakage measurement for automating testing

$\textbf{DYNAMIC ELECTRICAL CHARACTERISTICS} \; (\textbf{T}_{amb} = 25^{\circ} \textbf{C}, \;\; \textbf{C}_{L} = 50 \text{pF}, \; \textbf{R}_{L} = 200 \text{K}\Omega, \;\; \textbf{t}_{f} = \textbf{t}_{f} = 20 \; \text{ns})$

		Test Condition							Value*		Unit
Symbol	Parameter	V _C (V)	R _L (ΚΩ)	f _I (KHz)	V _I (V)	V _{SS} (V)	V _{DD} (V)		Тур.	Max.	
SWITCH	•								l.	l.	
t _{pd}	Propagation Delay						5		30	60	
	Time (Signal Input	$= V_{DD}$	200			0	10		15	30	ns
	to Output)						15		11	20	
	Frequency Response Channel "ON" (Sine Wave							V _O at Common Out/In	14		
	Input) at	= V _{DD}	1		5 (•)	0	10	V _O at Any Chan- nel	60		ns
	$20 \text{ Log } \frac{V_{O}}{V_{I}} = -3 \text{dB}$							nei			
	Feedthrough (All channels OFF) at		_		5 ()		4.0	V _O at Common Out/In	20		
	$20 \text{ Log } \frac{V_O}{V_I} = -40 \text{dB}$	= V _{SS}	1		5 (•)	0	10	V _O at Any Chan- nel	8		MHz
	Frequency Signal Crosstalk at	V _{C(A)} =V _{DD}	1		F (-)	0	10	Between Any two	4		MHz
	$20 \text{ Log} \frac{V_{O(A)}}{V_{I(B)}} = -40 \text{dB}$	V _{C(B)} =V _{SS}	'		5 (•)	U	10	(A and B) Channels	1		IVITZ
t _W	Sine Wave	5			2 (•)		5		0.3		
	Distortion (f _{IS} =	10	10	1	3 (•)	0	10		0.2		%
	1KHz sine wave)	15			5 (•)		15		0.12		
CONTRO	L(Address or Inhibit)										
t _{PLH} , t _{PHL}	Propagation Delay						5		325	650	
	Time:Address or Inhibit to Signal	l —	1			0	10		135	270	ns
	OUT (Channel Turning ON)		'			O	15		95	190	113
t _{PLH} , t _{PHL}	Propagation Delay						5		220	440	
	Time:Address or		0.0			0	10		90	180	
	Inhibit to Signal OUT (Channel Turning OFF)		0.3			U	15		65	130	ns
	Address or Inhibit to Signal Crosstalk		10**			0	10		75		mV peak

^(*) Typical temperature coefficient for all V_{DD} value is 0.3 %/°C (**): Both Ends of Channel (•): Peak to Peak voltage symmetrical about (V_{DD} - V_{SS}) / 2

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APPLICATION INFORMATION

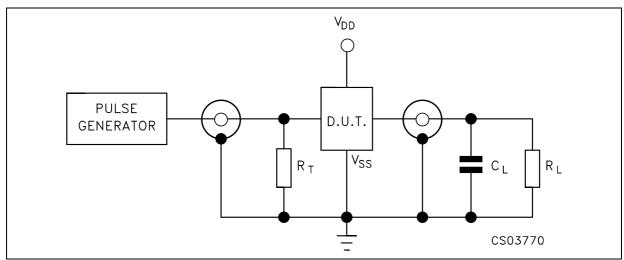
In applications where separate power sources are used to drive V_{DD} and the signal inputs, the V_{DD} current capability should exceed V_{DD}/R_L ($R_L =$ effective external load). This provision avoids permanent current flow or clamp action on the V_{DD} supply when power is applied or removed from the HCF4067B.

When switching from one address to another, some of the ON periods of the channels of the multiplexers will overlap momentarily, which may be objectionable in certain applications. Also, when a channel is turned ON or OFF by an address input, there is a momentary conductive path from the channel to V_{SS}, which will dump some charge from any capacitor connected to the input or output of the channel. The inhibit input turning on a channel will similarly dump some charge to V_{SS}.

The amount of charge dumped is mostly a function of the signal level above V_{SS}. Typically, at V_{DD} - V_{SS} = 10V, a 100 pF capacitor connected to the input or output of the channel will lose 3-4% of its voltage at the moment the channel turns ON or OFF. This loss of voltage is essentially independent of the address or inhibit signal transition time, if the transition time is less than 1-2 ms. When the inhibit signal turns a channel off, there is no change dumping of VSS. Rather, there is a slight rise in the channel voltage level (65 mV typ.) due to the capacitance coupling from inhibit input to channel input or output. Address input also couple some voltage steps onto the channel signal levels.

In certain applications, the external load-resistor current may include both V_{DD} and signal line components. To avoid drawing V_{DD} current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0.8V (calculated from RON values shown in **ELECTRICAL** CHARACTERISTICS CHART). No V_{DD} current will flow through R_L if the switch current flows into terminal 1 on the HCF4067B.

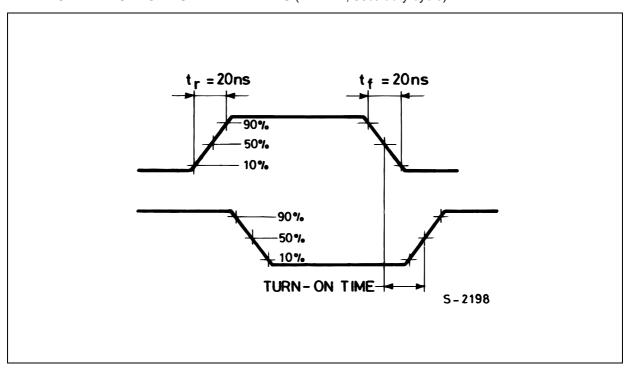
TEST CIRCUIT



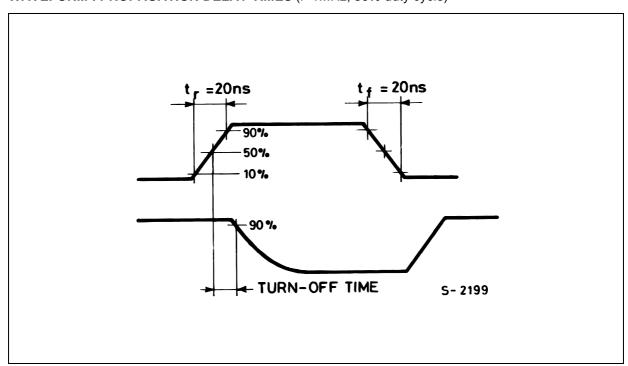
C_L = 50pF or equivalent (includes jig and probe capacitance)

 $R_L = 200 \text{K}\Omega$ $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

WAVEFORM: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



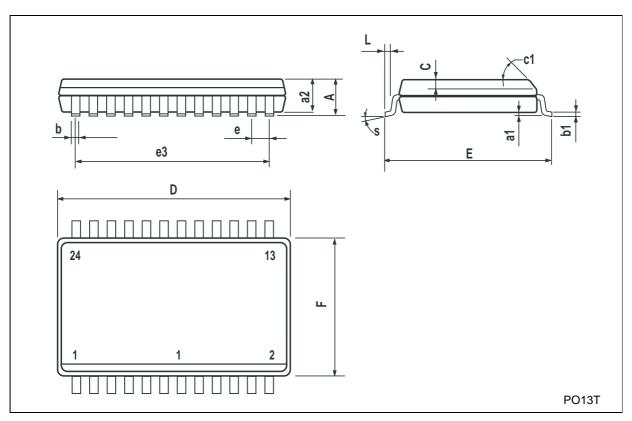
WAVEFORM: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



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SO-24 MECHANICAL DATA

DIM		mm.		inch					
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.			
А			2.65			0.104			
a1	0.1		0.2	0.004		0.008			
a2			2.45			0.096			
b	0.35		0.49	0.014		0.019			
b1	0.23		0.32	0.009		0.012			
С		0.5			0.020				
c1			45°	(typ.)	 	!			
D	15.20		15.60	0.598		0.614			
E	10.00		10.65	0.393		0.419			
е		1.27			0.050				
e3		13.97			0.550				
F	7.40		7.60	0.291		0.300			
L	0.50		1.27	0.020		0.050			
S			8° (r	nax.)	I	<u> </u>			



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